NSN 5961-00-406-3074

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-406-3074

view Offilite at https://aerobasegroup.com/his//0301-00-400-3074
Inclosure Material:
Metal
Overall Length:
0.260 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.370 inches
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
T0-39
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
75.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown
voltage, emitter-to-base, collector open
Current Rating Per Characteristic:
800.00 milliamperes source cutoff current
Power Rating Per Characteristic:
3.0 watts small-signal input power, common-collector preset
Transfer Ratio:
50.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead

NI/o

Shelf Life:

Specification Data:

81349-mil-s-19500/251 government specification

NSN 5961-00-406-3074

Transistor - Page 2 of 2



		• •			
ш	ın	10	<i>(</i>)+	Measure:	

--

Demilitarization:

No

Fiig:

A110a0